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#### Simulated Performance of the SiD Digital ECal Based on Monolithic Active Pixel Sensors

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on behalf of the SiD MAPS Collaboration (M. Breidenbach, A.Habib, L. Rota, C.Vernieri et al.)

"The SiD Digital ECal Based on Monolithic Active Pixel Sensors", 10.3390/instruments6040051, Instruments, 6, 51 (2022)



# SiD Digital ECal Based on MAPS

- Upgrade ILC TDR design to replace sensors with 13 mm<sup>2</sup> analog pixels with 25 x 100 um<sup>2</sup> (or 25 x 50 um<sup>2</sup>) digital pixels.
- \* How well can we measure energy and shower structure with digital system:
  - \* Compared to SiD baseline of analog measurements.
  - \* Can the detailed structural measurements be used to improve measurement?
  - \* Would a neural net optimization offer an improvement?
- \* What are the limits of transverse separation and measurement?

#### Large area MAPS for SiD tracker & ECal

#### **Benefits of large-area MAPS:**

- Standard CMOS foundry, low resistivity: cost abla
- Sensing element and readout electronics on same die
  - In-pixel amplification: noise ↓, power ↓
  - No need for bump-bonding: cost au
- Area >  $10x10 \text{ cm}^2 \rightarrow$  enable O(1) m<sup>2</sup> modules

#### Several design challenges:

- Large on-die variations, mismatch
- Yield
- Stitching layout rules
- Distribution of power supply
- Distribution of global control signals/references



An example of the SiD Tracker and the ECal overall design

# Goals of R&D: find solutions and explore novel design techniques

SLAC

#### Main specifications for Large Area MAPS development

TID-AIR

Parameter	Value	Notes	L. Rota		JLAC
Min Threshold	140 e <sup>-</sup>	0.25*MIP with 10 µm thick	epi layer		25 x 100 µm <sup>2</sup>
Spatial resolution	7 µm	In bend plane, based on S specs	iD tracker		ECal performance same as
Pixel size	25 x 100 µm <sup>2</sup>	Optimized for tracking (note:	25 x 50 µm²)		50 x 50 µm²
Chip size	10 x 10 cm <sup>2</sup>	Requires stitching on 4 sid	es		
Chip thickness	300 µm	<200 µm for tracker. Could b for EMCal to improve yield.	e 300 µm		
Timing resolution (pixel)	~ ns	Bunch spacing: C <sup>3</sup> stricte 5.3->3.5 ns; ILC is 554 ns	st with		Ecal
Total lonizing Dose	100 kRads	Total lifetime dose, not a co	oncern		
Hit density / train	1000 hits / cm <sup>2</sup>				
Hits spatial distribution	Clusters	Due to jets			
Balcony size	1 mm	Only on one side, where we bonding pads will be located	ire- ed.	SiD Tracker and the ECa	today
Power density	20 mW / cm <sup>2</sup>	Based on SiD tracker power consumption: 400W over 6	er 67m²	A. Habib & C	C. Vernieri <sup>4</sup>



![](_page_5_Figure_0.jpeg)

SiD Digital ECal

# Resolution vs. Energy (hits & mips)

#### Resolution vs. Energy (hits & mips)

Gamma Resolution vs. Energy (B=5T)

![](_page_6_Figure_3.jpeg)

![](_page_7_Figure_0.jpeg)

al ECal

 Counting clusters should reduce hit fluctuations

# Resolution vs. Energy (hits/clusters/mips)

![](_page_8_Figure_1.jpeg)

Simple cluster performance is better than hit counting.

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![](_page_9_Picture_0.jpeg)

#### Mips/cluster $10 \text{ GeV } \gamma \text{s} - 2000 \text{ showers}$

![](_page_10_Figure_1.jpeg)

![](_page_11_Picture_0.jpeg)

#### $10 \text{ GeV } \gamma \text{s} - 2000 \text{ showers}$

Clusters wt (radius,size) RadWt vs. mips

![](_page_11_Figure_3.jpeg)

Apply weight to clusters:

RadWt =  $a \exp(-bR) + c$ 

a,b,c = f(CISz)

### Resolution vs. Energy (hits/clusters/mips)

Resolution vs. Energy (hits/clusters/mips) & weighted clusters. clusters cntHist 2000 Entries <sup>™</sup> 180 E10 GeV 938.9 /lean 47 29 Std Dev 4.9% = 5.0% 140 Gaussian Fit: 120F 938.0 +/- 45.8 clu (4.9%) 100 80 F 60 40 F 1000 950 900 1050 850 800 wtd clusters clustersWtdHist <sup>5</sup> 250 10 GeV 630.9 Mean Std Dev 27.41 ₂₀₀<sup>⊑</sup>4.3% = 4.3% issian Fit 631.3 +/- 26.9 clusters (4.3%) 150 100 50 600 650 700 800 wtd clusters

Gamma Resolution vs. Energy (B=5T)

![](_page_12_Figure_3.jpeg)

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![](_page_13_Picture_0.jpeg)

### TMVA Neural Net

TRAINING - 10 GeV 2000 events 2,502,000 hits 1,878,999 clusters

# Store model to file model.save('modelRegression%s.h5'%Efact) model.summary()

# Book methods

factory.BookMethod(dataloader, TMVA.Types.kPyKeras, 'PyKeras',

'H:!

V:VarTransform=D,G:FilenameModel=modelRegression%s.h5:FilenameTrainedModel= trainedModelRegression%s.h5:NumEpochs=20:BatchSize=32'%(Efact,Efact))

Neural net cluster weighting based on 1. Three input parameters = Cluster size,layer num,shower radius 2. Five input parameters = Add cluster length in Y and Z Weighted function vs. TMVA neural net (10 GeV  $\gamma$ s)

![](_page_14_Figure_1.jpeg)

![](_page_14_Figure_2.jpeg)

![](_page_15_Picture_0.jpeg)

# **Results: Energy Resolution**

Energy	1	2	5	10	20	50
clusters	13.8%	10.1%	6.6%	4.9%	3.7%	2.7%
wtd clusters	12.3%	8.8%	5.7%	4.4%	3.2%	2.2%
3 par TMVA	12.6%	9.5%	6.2%	4.4%	3.4%	2.2%
5 par TMVA	12.8%	9.4%	5.9%	4.3%	3.1%	2.2%

\* Weight fits for 2, 10, 50 GeV; extrapolated for 1, 5, 20 GeV.

- NN optimized for each energy
- \* 3 par = cluster size, layer, radius
- \* 5 par = cluster size, layer, radius, dY, dZ

Weighted clusters already achieve performance of this neural net.

![](_page_16_Figure_0.jpeg)

#### Multi-shower of SiD MAPS compared to SiD TDR $40 \text{ GeV } \pi^0 \rightarrow \text{two } 20 \text{ GeV } \gamma$ 's

![](_page_17_Figure_1.jpeg)

![](_page_17_Figure_2.jpeg)

New SiD fine pixel sensors 25 μm x 100 μm pixels

SiD TDR hexagonal sensors 13 mm<sup>2</sup> pixels

SiD Digital ECal based on Silicon MAPS

![](_page_18_Figure_0.jpeg)

![](_page_19_Picture_0.jpeg)

#### $\gamma$ 's in jet / SiD baseline ECal (13mm<sup>2</sup> pixels)

![](_page_19_Figure_2.jpeg)

- \* 13 mm<sup>2</sup> pixels of analog SiD ECal
- \* 5000x granularity with digital MAPS ECal
- \* Upcoming integration into SiD simulation will define scale of improvement?

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![](_page_20_Picture_0.jpeg)

# Conclusion

- Application of monolithic active pixel sensors (MAPS) to SiD digital ECal offers excellent performance:
  - Energy measurement
  - Transverse energy containment & multiple shower separation
- \* The well defined structure of EM showers allows simple algorithmic improvement in energy measurement.
- Neural nets have been studied to improve energy measurement:
  - \* They have not yet provided improvement over the "informed" algorithm.
- \* Future simulation of full SiD detector with high granularity of MAPS ECal